

Features

- 8-Bit Multiplexed Addresses/Outputs
- Fast Read Access Time - 90 ns
- Dual Voltage Range Operation
 - Low-Voltage Power Supply Range, 3.0V to 3.6V, or
 - Standard 5V \pm 10% Supply Range
- Low Power CMOS Operation
 - 20 μ A max. Standby for ALE = V_{IH} and V_{CC} = 3.6V
 - 29 mW max. Active at 5 MHz for V_{CC} = 3.6V
- 20-Lead TSSOP Package
- High Reliability CMOS Technology
 - 2,000V ESD Protection
 - 200 mA Latchup Immunity
- Rapid™ Programming Algorithm - 50 μ s/byte (typical)
- CMOS and TTL Compatible Inputs and Outputs
 - JEDEC Standard for LVTTTL
- Integrated Product Identification Code
- Commercial and Industrial Temperature Range

Description

The AT27LV520 is a low-power, high-performance 524,288-bit one-time programmable read only memory (OTP EPROM) organized 64K by 8 bits. It incorporates latches for the 8 lower order address bits to multiplex with the 8 data bits. This minimizes system chip count, reduces cost, and simplifies the design of multiplexed bus systems. It requires only one power supply in the range of 3.0V to 3.6V for normal read mode operation, making it ideal for fast, portable systems using battery power. Any byte can be accessed in less than 90 ns.

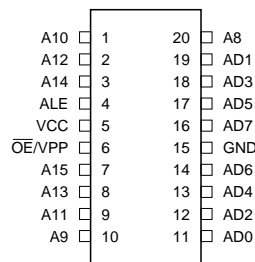
The AT27LV520 is available in 173 mil, 20-pin TSSOP, 300 mil, 20-pin SOIC and 28-pin TSOP, one-time programmable (OTP) plastic packages.

(continued)

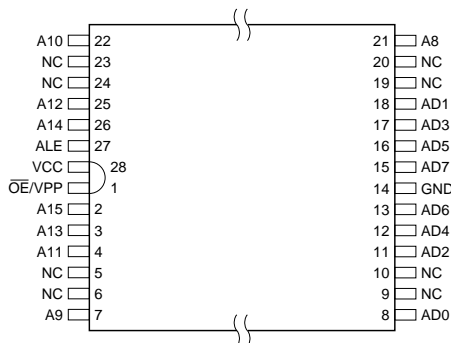
Pin Configurations

Pin Name	Function
A8 - A15	Addresses
AD0 - AD7	Addresses/Outputs
$\overline{\text{OE}}/V_{PP}$	Output Enable/V _{PP}
ALE	Address Latch Enable

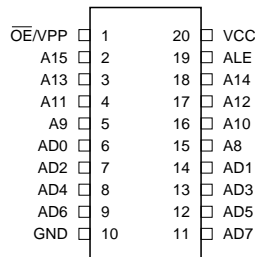
TSSOP Top View



TSOP Top View



SOIC Top View



**512K (64K x 8)
Multiplexed
Addresses/
Outputs
Low Voltage
OTP EPROM**

AT27LV520



Atmel's innovative design techniques provide fast speeds that rival 5V parts while keeping the low power consumption of a 3.3V supply. At $V_{CC} = 3.0V$, any byte can be accessed in less than 90 ns. With a typical power dissipation of only 18 mW at 5 MHz and $V_{CC} = 3.3V$, the AT27LV520 consumes less than one fifth the power of a standard 5V EPROM. Standby mode is achieved by asserting ALE high. Standby mode supply current is typically less than 1 μA at 3.3V.

The AT27LV520 operating with V_{CC} at 3.0V produces TTL level outputs that are compatible with standard TTL logic devices operating at $V_{CC} = 5.0V$. The device is also capable of standard 5-volt operation making it ideally suited for dual supply range systems or card products that are plugable in both 3-volt and 5-volt hosts.

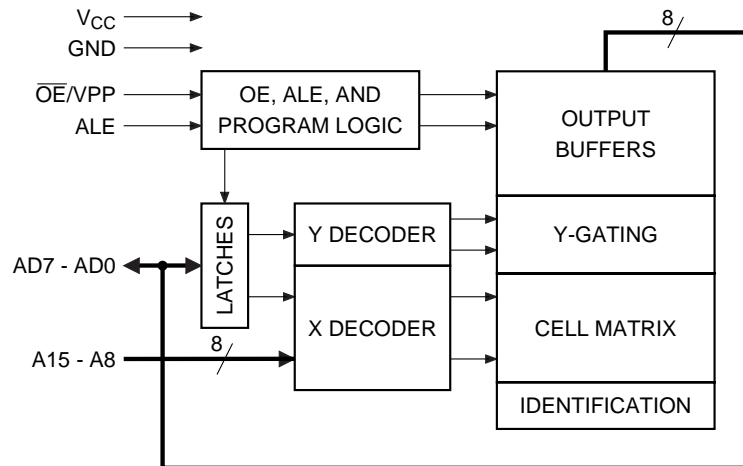
Atmel's AT27LV520 has additional features to ensure high quality and efficient production use. The Rapid™ Programming Algorithm reduces the time required to program the part and guarantees reliable programming. Programming time is typically only 50 μs /byte. The Integrated Product Identification Code electronically identifies the device and

manufacturer. This feature is used by industry standard programming equipment to select the proper programming algorithms and voltages. The AT27LV520 programs exactly the same way as a standard 5V AT27C520 and uses the same programming equipment.

System Considerations

Switching under active conditions may produce transient voltage excursions. Unless accommodated by the system design, these transients may exceed data sheet limits, resulting in device non-conformance. At a minimum, a 0.1 μF high frequency, low inherent inductance, ceramic capacitor should be utilized for each device. This capacitor should be connected between the V_{CC} and Ground terminals of the device, as close to the device as possible. Additionally, to stabilize the supply voltage level on printed circuit boards with large EPROM arrays, a 4.7 μF bulk electrolytic capacitor should be utilized, again connected between the V_{CC} and Ground terminals. This capacitor should be positioned as close as possible to the point where the power supply is connected to the array.

Block Diagram



Absolute Maximum Ratings*

Temperature Under Bias	-55°C to +125°C
Storage Temperature	-65°C to +150°C
Voltage on Any Pin with Respect to Ground	-2.0V to +7.0V ⁽¹⁾
Voltage on A9 with Respect to Ground	-2.0V to +14.0V ⁽¹⁾
V _{PP} Supply Voltage with Respect to Ground	-2.0V to +14.0V ⁽¹⁾

*NOTICE: Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note: 1. Minimum voltage is -0.6V DC which may undershoot to -2.0V for pulses of less than 20 ns. Maximum output pin voltage is V_{CC} + 0.75V DC which may overshoot to +7.0V for pulses of less than 20 ns.

Operating Modes

Mode/Pin	ALE	\overline{OE}/V_{PP}	A8 - A15	AD0 - AD7
Read ⁽²⁾	V _{IL}	V _{IL}	Ai	D _{OUT}
Output Disable ⁽²⁾	V _{IL} /V _{IH}	V _{IH}	X ⁽¹⁾	High Z/A0 - A7
Standby	V _{IH}	V _{IH}	Ai	A0 - A7
Address Latch Enable ⁽²⁾	V _{IH}	V _{IH}	X	A0 - A7
Rapid Program ⁽³⁾	V _{IH}	V _{PP}	Ai	D _{IN}
Product Identification ⁽⁴⁾	V _{IL}	V _{IL}	A9 = V _H ⁽⁵⁾ A8 = V _{IH} or V _{IL} A10 - A15 = V _{IL}	Identification Code

- Notes:
1. X can be V_{IL} or V_{IH}.
 2. Read, output disable, and standby modes require 3.0V ≤ V_{CC} ≤ 3.6V, or 4.5V ≤ V_{CC} ≤ 5.5V.
 3. Refer to Programming Characteristics.
 4. V_H = 12.0 ± 0.5V.
 5. Two identifier bytes may be selected. All A8 - A15 inputs are held low (V_{IL}), except A9 which is set to V_H and A8 which is toggled low (V_{IL}) to select the Manufacturer's Identification byte and high (V_{IH}) to select the Device Code byte.



DC and AC Operating Conditions for Read Operation

		AT27LV520-90
Operating Temp. (Case)	Com.	0°C - 70°C
	Ind.	-40°C - +85°C
V _{CC} Supply		3.0V to 3.6V
		5V ± 10%

DC and Operating Characteristics for Read Operation

Symbol	Parameter	Condition	Min	Max	Units
V_{CC} = 3.0V to 3.6V					
I _{LI}	Input Load Current	V _{IN} = 0V to V _{CC}		±1	μA
I _{LO}	Output Leakage Current	V _{OUT} = 0V to V _{CC}		±5	μA
I _{SB} ⁽¹⁾	V _{CC} Standby Current	ALE = V _{CC} ± 0.3V; Ai, ADi = GND/V _{CC} ± 0.3V		20	μA
I _{CC}	V _{CC} Active Current	f = 5 MHz, I _{OUT} = 0 mA, ALE = V _{IL}		8	mA
V _{IL}	Input Low Voltage		-0.6	0.8	V
V _{IH}	Input High Voltage		2.0	V _{CC} + 0.5	V
V _{OL}	Output Low Voltage	I _{OL} = 2.0 mA		0.4	V
V _{OH}	Output High Voltage	I _{OH} = -2.0 mA	2.4		V
V_{CC} = 4.5V to 5.5V					
I _{LI}	Input Load Current	V _{IN} = 0V to V _{CC}		±1	μA
I _{LO}	Output Leakage Current	V _{OUT} = 0V to V _{CC}		±5	μA
I _{SB} ⁽¹⁾	V _{CC} Standby Current	ALE = V _{CC} ± 0.3V; Ai, ADi = GND/V _{CC} ± 0.3V		100	μA
I _{CC}	V _{CC} Active Current	f = 5 MHz, I _{OUT} = 0 mA, ALE = V _{IL}		20	mA
V _{IL}	Input Low Voltage		-0.6	0.8	V
V _{IH}	Input High Voltage		2.0	V _{CC} + 0.5	V
V _{OL}	Output Low Voltage	I _{OL} = 2.1 mA		0.4	V
V _{OH}	Output High Voltage	I _{OH} = -400 μA	2.4		V

Note: V_{CC} standby current will be slightly higher with ALE, Ai, and ADi at TTL levels.

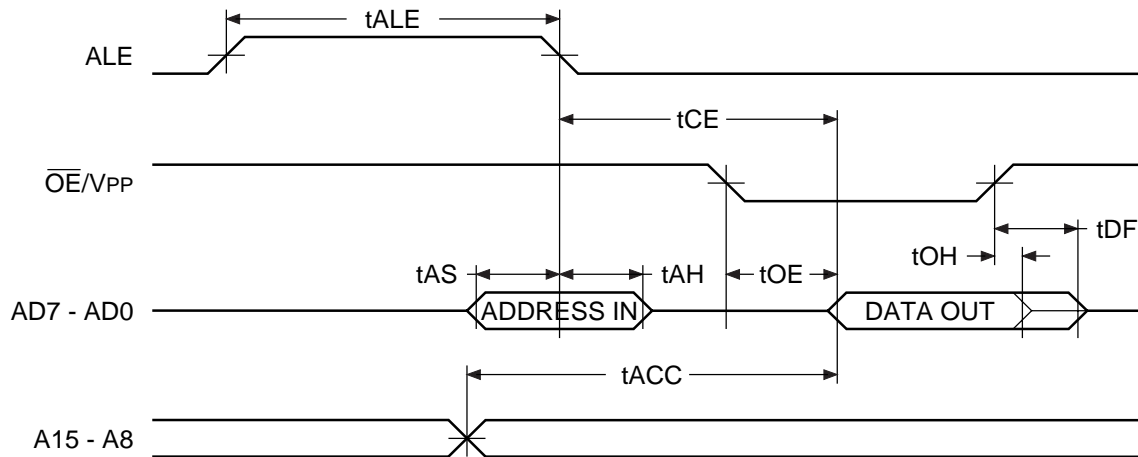
AC Characteristics for Read Operation

V_{CC} = 3.0V to 3.6V and 4.5V to 5.5V

Symbol	Parameter	Condition	AT27LV520-90		Units
			Min	Max	
t _{ACC} ⁽³⁾	Address to Output Delay	ALE = $\overline{OE}/V_{PP} = V_{IL}$		90	ns
t _{CE}	Address Latch Enable Low to Output Delay	Address Valid		70	ns
t _{AS}	Address Setup Time	$\overline{OE}/V_{PP} = V_{IH}$	15		ns
t _{AH}	Address Hold Time	$\overline{OE}/V_{PP} = V_{IH}$	15		ns
t _{ALE}	Address Latch Enable Width	$\overline{OE}/V_{PP} = V_{IH}$	45		ns
t _{OE} ⁽³⁾	\overline{OE}/V_{PP} to Output Delay	ALE = V _{IL}		35	ns
t _{DF} ⁽⁴⁾⁽⁵⁾	\overline{OE}/V_{PP} High to Output Float	ALE = V _{IL}		25	ns
t _{OH}	Output Hold from Address or \overline{OE}/V_{PP} whichever occurred first	ALE = V _{IL}	0		ns

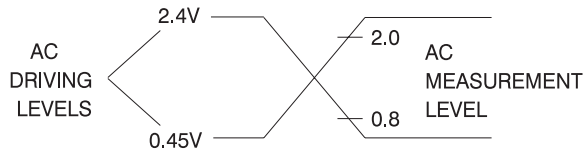
Notes: 2, 3, 4 — see AC Waveforms for Read Operation

AC Waveforms for Read Operation⁽¹⁾



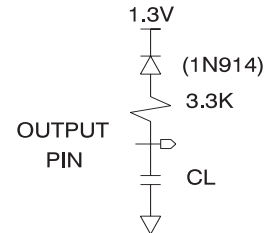
- Notes:
1. Timing measurement reference levels for all speed grades are $V_{OL} = 0.8V$ and $V_{OH} = 2.0V$. Input AC drive levels are $V_{IL} = 0.45V$ and $V_{IH} = 2.4V$.
 2. \overline{OE}/V_{PP} may be delayed up to $t_{CE} - t_{OE}$ after the address is valid without impact on t_{CE} .
 3. \overline{OE}/V_{PP} may be delayed up to $t_{ACC} - t_{OE}$ after the address is valid without impact on t_{ACC} .
 4. This parameter is only sampled and is not 100% tested.
 5. Output float is defined as the point when data is no longer driven.

Input Test Waveforms and Measurement Levels



$t_R, t_F < 20$ ns (10% to 90%)

Output Test Load



Note: $C_L = 100$ pF including jig capacitance.

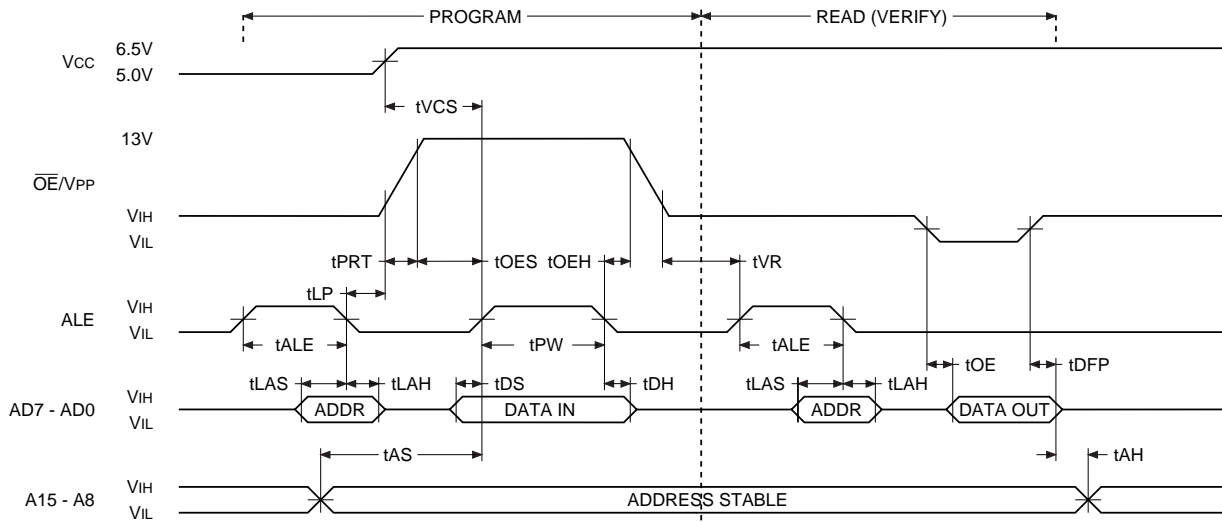
Pin Capacitance^(Note:)

($f = 1$ MHz, $T = 25^\circ C$)

	Typ	Max	Units	Conditions
C_{IN}	4	6	pF	$V_{IN} = 0V$
C_{OUT}	8	12	pF	$V_{OUT} = 0V$

Note: Typical values for nominal supply voltage. This parameter is only sampled and is not 100% tested.

Programming Waveforms



- Notes:
1. The Input Timing Reference is 0.8V for V_{IL} and 2.0V for V_{IH} .
 2. t_{OE} and t_{DFP} are characteristics of the device but must be accommodated by the programmer.

DC Programming Characteristics

$T_A = 25 \pm 5^\circ\text{C}$, $V_{CC} = 6.5 \pm 0.25\text{V}$, $\overline{OE}/V_{PP} = 13.0 \pm 0.25\text{V}$

Symbol	Parameter	Test Conditions	Limits		Units
			Min	Max	
I_{LI}	Input Load Current	$V_{IN} = V_{IL}, V_{IH}$		± 10	μA
V_{IL}	Input Low Level		-0.6	0.8	V
V_{IH}	Input High Level		2.0	$V_{CC} + 1.0$	V
V_{OL}	Output Low Voltage	$I_{OL} = 2.1 \text{ mA}$		0.4	V
V_{OH}	Output High Voltage	$I_{OH} = -400 \mu\text{A}$	2.4		V
I_{CC2}	V_{CC} Supply Current (Program and Verify)			25	mA
I_{PP2}	\overline{OE}/V_{PP} Current	$\text{ALE} = V_{IH}$		25	mA

AC Programming Characteristics*

$T_A = 25 \pm 5^\circ\text{C}$, $V_{CC} = 6.5 \pm 0.25\text{V}$, $\overline{OE}/V_{PP} = 13.0 \pm 0.25\text{V}$

Symbol	Parameter ⁽¹⁾	Test Conditions	Limits		Units
			Min	Max	
t _{ALE}	Address Latch Enable Width	Input Rise and Fall Times (10% to 90%) 20 ns Input Pulse Levels 0.45V to 2.4V Input Timing Reference Level 0.8V to 2.0V Output Timing Reference Level 0.8V to 2.0V	500		ns
t _{LAS}	Latched Address Setup Time		100		ns
t _{LAH}	Latched Address Hold Time		100		ns
t _{LP}	ALE Low to \overline{OE}/V_{PP} High Voltage Delay		2		μs
t _{OES}	\overline{OE}/V_{PP} Setup Time		2		μs
t _{OEH}	\overline{OE}/V_{PP} Hold Time		2		μs
t _{DS}	Data Setup Time		2		μs
t _{DH}	Data Hold Time		2		μs
t _{PW}	ALE Program Pulse Width ⁽²⁾		47.5	52.5	μs
t _{VR}	\overline{OE}/V_{PP} Recovery Time		2		μs
t _{VCS}	V _{CC} Setup Time		2		μs
t _{OE}	Data Valid from \overline{OE}/V_{PP}			150	ns
t _{D_{FP}}	\overline{OE}/V_{PP} High to Output Float Delay ⁽⁴⁾		0	130	ns
t _{AS}	Address Setup Time		2		μs
t _{AH}	Address Hold Time		0		μs
t _{PRT}	\overline{OE}/V_{PP} Pulse Rise Time During Programming	50		ns	

- Notes: 1. V_{CC} must be applied simultaneously or before \overline{OE}/V_{PP} and removed simultaneously or after \overline{OE}/V_{PP}
 2. Program Pulse width tolerance is 50 μsec ± 5%.
 3. This parameter is only sampled and is not 100% tested. Output Float is defined as the point where data is no longer driven — see timing diagram.

Atmel's 27LV520 Integrated Product Identification Code

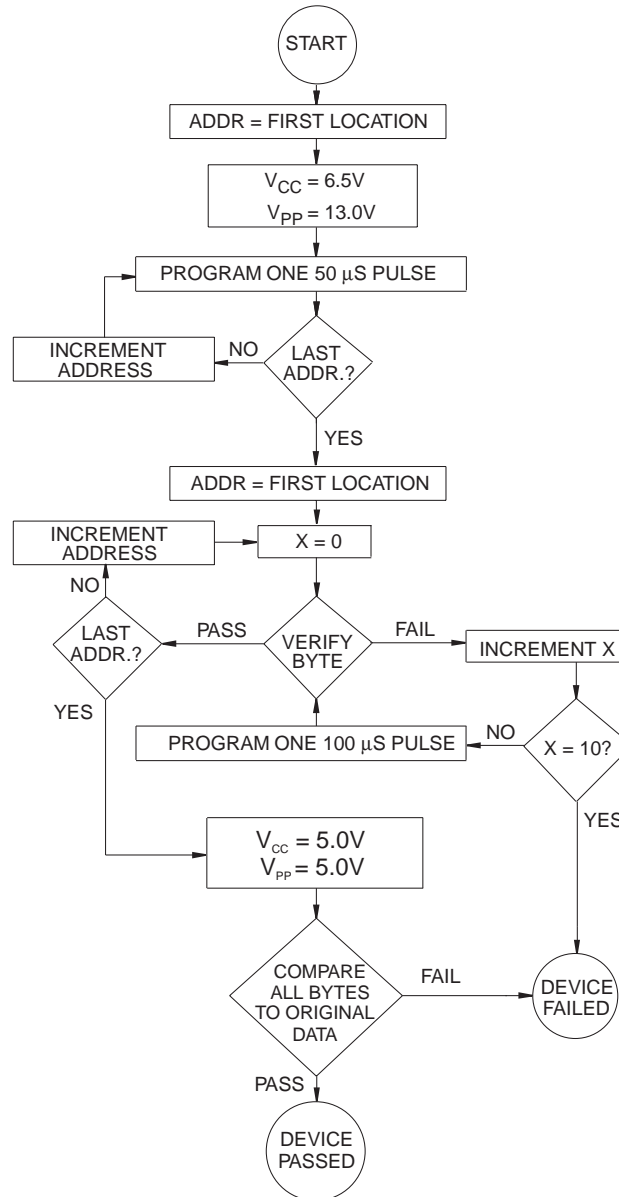
Codes	Pins									Hex Data
	A8	AD7	AD6	AD5	AD4	AD3	AD2	AD1	AD0	
Manufacturer	0	0	0	0	1	1	1	1	0	1E
Device Type	1	1	0	0	1	1	1	0	1	9D



Rapid™ Programming Algorithm

A 50 μs ALE pulse width is used to program. The address is set to the first location. V_{CC} is raised to 6.5V and \overline{OE}/V_{PP} is raised to 13.0V. Each address is first programmed with one 50 μs ALE pulse without verification. Then a verification/reprogramming loop is executed for each address. In the event a byte fails to pass verification, up to 10 successive 50 μs pulses are applied with a verification after each

pulse. If the byte fails to verify after 10 pulses have been applied, the part is considered failed. After the byte verifies properly, the next address is selected until all have been checked. \overline{OE}/V_{PP} is then lowered to V_{IH} and V_{CC} to 5.0V. All bytes are read again and compared with the original data to determine if the device passes or fails.



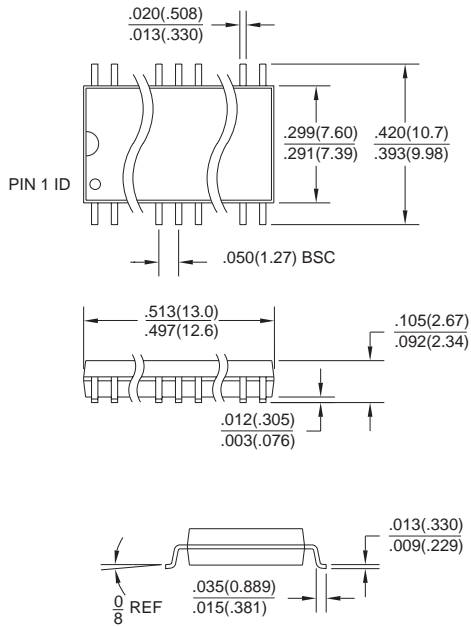
Ordering Information

t_{ACC} (ns)	I_{CC} (mA) Active	Ordering Code	Package	Operation Range
90	8	AT27LV520-90SC	20S	Commercial (0°C to 70°C)
		AT27LV520-90TC	28T	
		AT27LV520-90XC	20X	
90	8	AT27LV520-90SI	20S	Industrial (-40°C to +85°C)
		AT27LV520-90TI	28T	
		AT27LV520-90XI	20X	

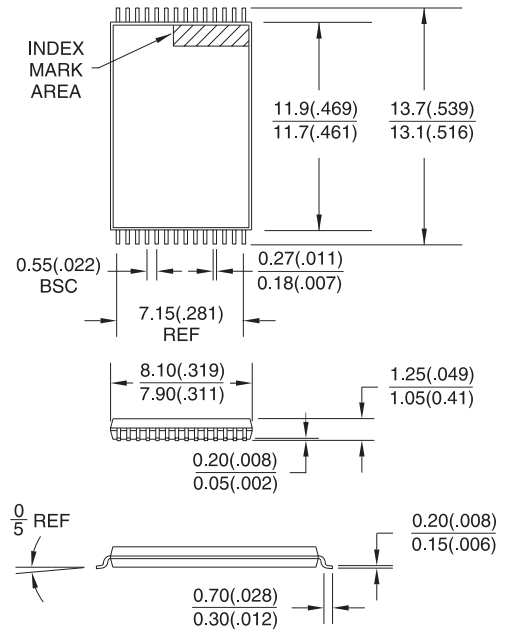
Package Type	
20S	20-Lead, 0.300" Wide, Plastic Gull-Wing Small Outline (SOIC)
28T	28-Lead, Thin Small Outline Package (TSOP)
20X	20-Lead, 0.173" Wide, Thin Shrink Small Outline (TSSOP)

Packaging Information

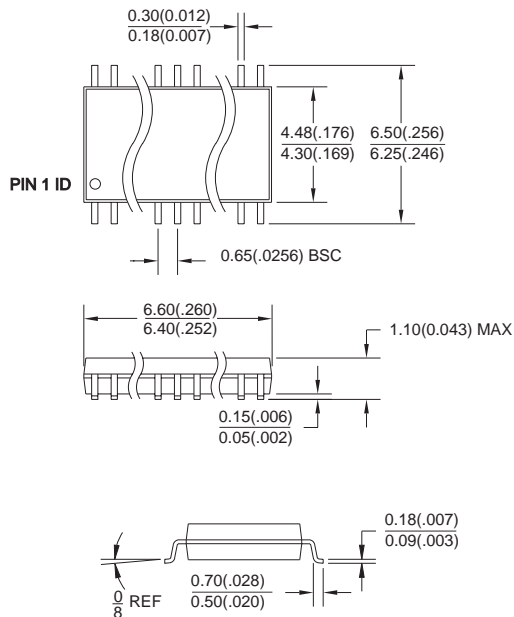
20S, 20-Lead, 0.300" Wide,
Plastic Gull Wing Small Outline
Dimensions in Inches and (Millimeters)



28T, 28-Lead, Plastic Thin Small Outline Package (TSOP)
Dimensions in Millimeters and (Inches)



20X, 20-Lead, 0.173" Wide, Thin Super Small Outline Package (TSSOP)
Dimensions in (Millimeters) and Inches



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